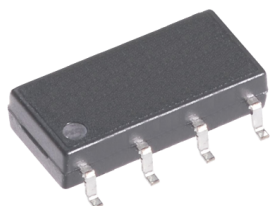
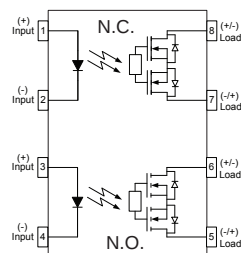




Parameter	Symbol	Rating	Units
Load Voltage	V_L	60	V
Load Current	I_L	0.4	A
On-Resistance	R_{on}	1	Ω
I/O Breakdown Voltage	V_{io}	2500	V_{rms}

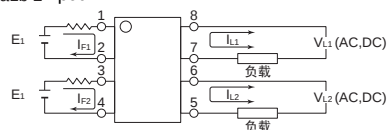


SOP-8

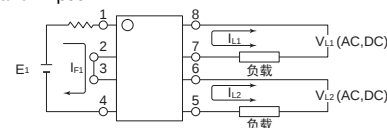


1,3. LED Anode
2,4. LED Cathode
5,6. Drain (MOS FET)
7,8. Drain (MOS FET)

(1) 1a1b 2input



(2) 1a1b 1input



APSEMI PhotoRelays

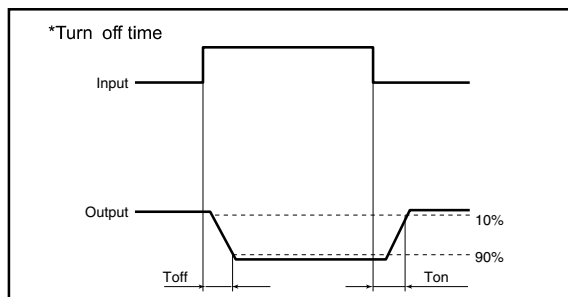
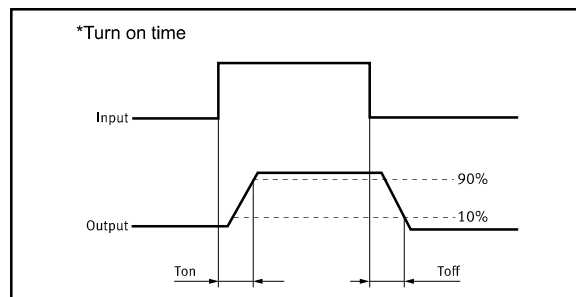
- Long life (No limit on mechanical and electrical lifetime) Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI
- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load
- switching
- Small package size

Applications

- Telecom/Datacom switching
- Multiplexers
- Meter reading systems
- Data acquisition
- Medical equipment
- Battery monitoring
- I/O Sub-Systems
- Robotics
- Aerospace
- Home/Safety security systems
- Process Control
- Energy Management
- Reed Relay EMR Replacement
- Programmable Controllers

TPYES

Category	Output Rating		Package	Part No.	Packing Quantity
	Load Voltage	Load Current			
AC/DC	60V	400mA	SOP-8	GAQW612S	2000pcs /reel



Absolute Maximum Ratings (Ta = 25°C)

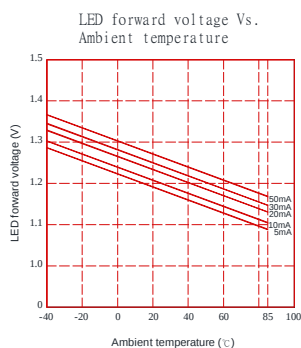
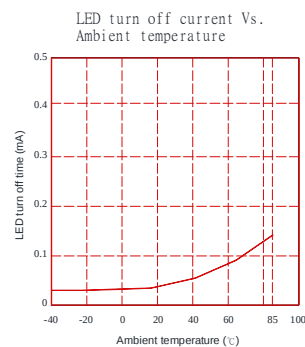
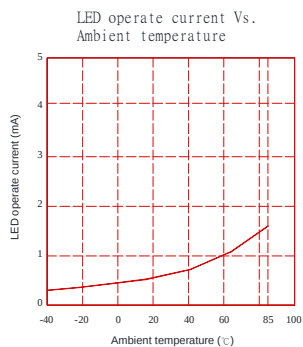
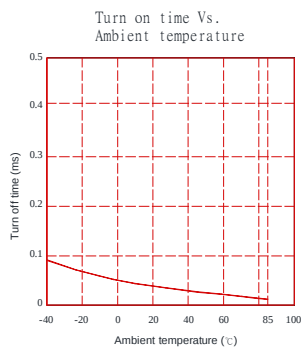
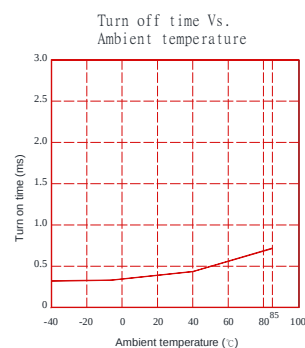
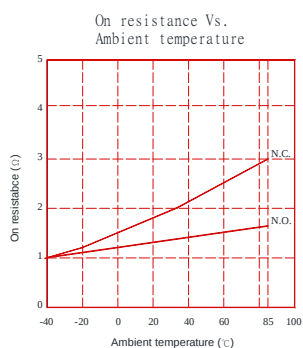
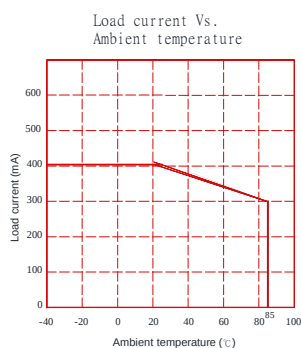
Item		Symbol	Value	Units	Note
Input	Continuous LED Current	IF	50	mA	
	Peak LED Current	IFP	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	Pin	75	mW	
Output	Load Voltage	VL	60	V(AC peak or DC)	
	Load Current	IL	400	mA	
	Peak Load Current	IPeak	1.0	A	1ms(1 pulse)
	Output Power Dissipation	Pout	450	mW	
Total Power Dissipation		PT	500	mW	
I/O Breakdown Voltage		VI/O	2500	Vrms	RH=60%, 1min
Operating Temperature		TOpr	-40 to +85	-40 to +85	
Storage Temperature		TStg	-40 to +100	-40 to +100	
Pin Soldering Temperature		TSol	260	260	10 sec max.

Electrical Characteristics (Ta = 25°C)

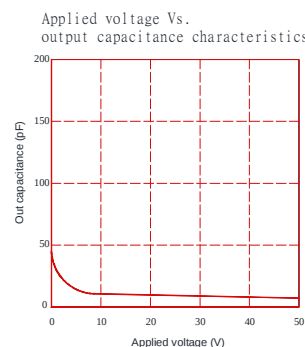
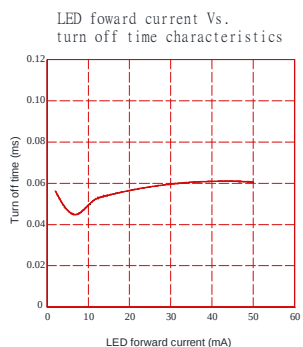
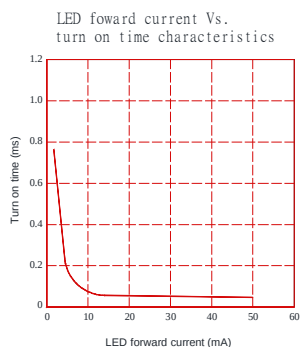
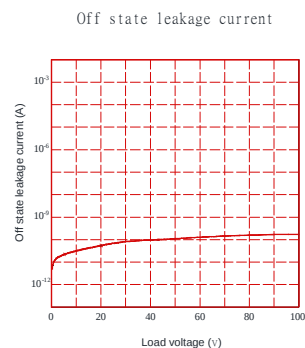
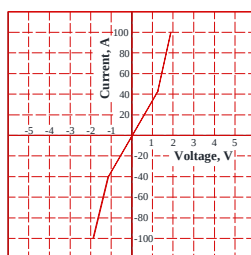
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	VF		1.2	1.4	V	IF=10mA
	Operation LED Current	IF On		0.5	3.0	mA	
	Recovery LED Current	IF Off		0.35	0.5	mA	
	Recovery LED Voltage	VF Off	0.5			V	
Output	On-Resistance	ROn		1(N.O.)	1.4(N.O.)	Ω	IF=5mA (N.O.) IF=0mA (N.C) IL=100mA Time to flow is within 1 sec.
				1(N.C.)	3(N.C.)		
	Off-State Leakage Current	ILeak			10	uA	IF=0mA (N.O.) IF=5mA (N.C) VL= Rating
	Output Capacitance	COut		165		pF	IF=5mA, VL=0, f=1MHz
Transmis sion	Turn-On Time	TOn		0.23(N.O.)	0.5(N.O.)	ms	IF=5mA, IL=Max
				0.02(N.C.)	1.0(N.C.)		
	Turn-Off Time	TOff		0.03(N.O.)	0.2(N.O.)	ms	
				0.5(N.C.)	3.0(N.C.)		
Coupled	I/O Isolation Resistance	RI/O	10 ¹⁰			Ω	DC500V
	I/O Capacitance	CI/O		0.8		pF	f=1MHz

Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value): IF ≥5mA and ≤30mA

Engineering Data

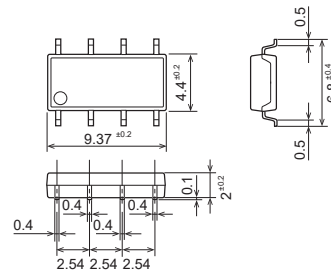
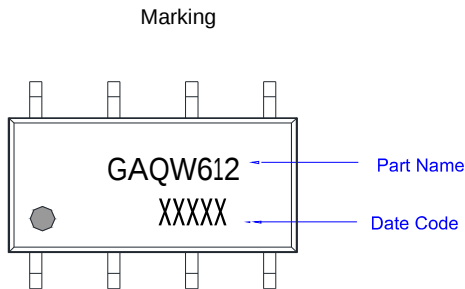


Voltage Vs. current characteristics of output at MOS portion

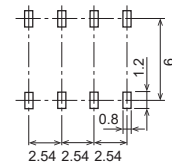


Dimensions and SOP-8 Package Unit: mm

Surface mount terminal type

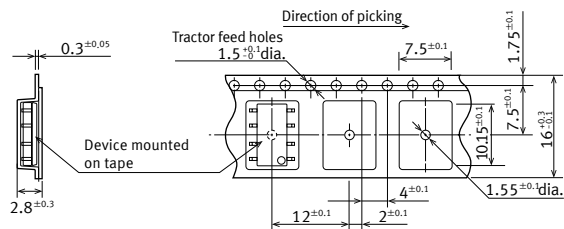


Recommended mounting pad
(Top view)

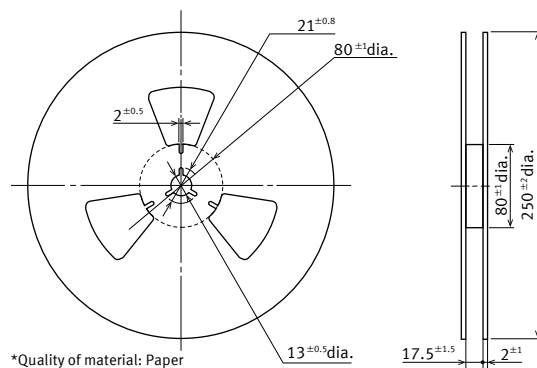


Tape dimensions (tape reel)

Tape dimensions (Unit: mm)

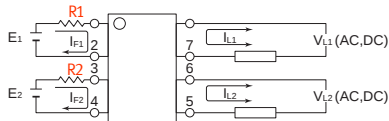


Dimensions of paper tape reel (Unit: mm)



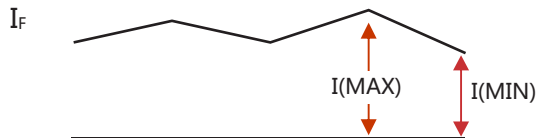
Using Methods

Examples of resistance value to control LED forward current ($I_F=5\text{mA}$)



E1 E2	R1 R2(Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9K Ω
24V	4.1K Ω

LED forward current must be more than 5mA , at $I(\text{MIN})$, and less than 30mA , at $I(\text{MAX})$.



Recommended Operating Conditions

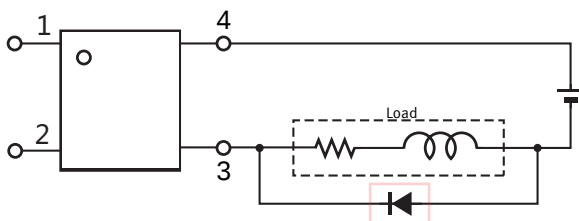
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

Characteristic	Symbol	Min	Typ.	Max	Unit
Forward current	I_F	5.0	7.0	30	mA

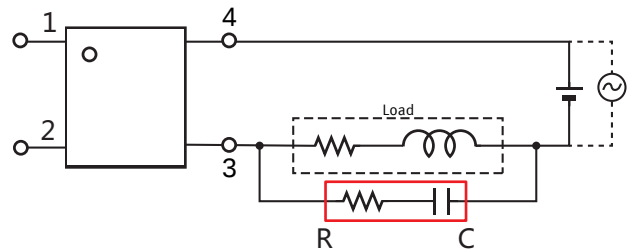
Protection Circuit

Output spike voltages:if an inductive load generates spike voltages which exceed heabsolute maximum rating, the spike voltage shall be limited.

Clamp diode is connected in parallel with the load.
Absorb capacity with external diode.



CR Snubber is connected in parallel with the load.
Absorb capacity with buffer capacity.



When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective.
Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.